

DUAL LOW NOISE OPERATIONAL AMPLIFIERS

AZ4580

Pin Configuration

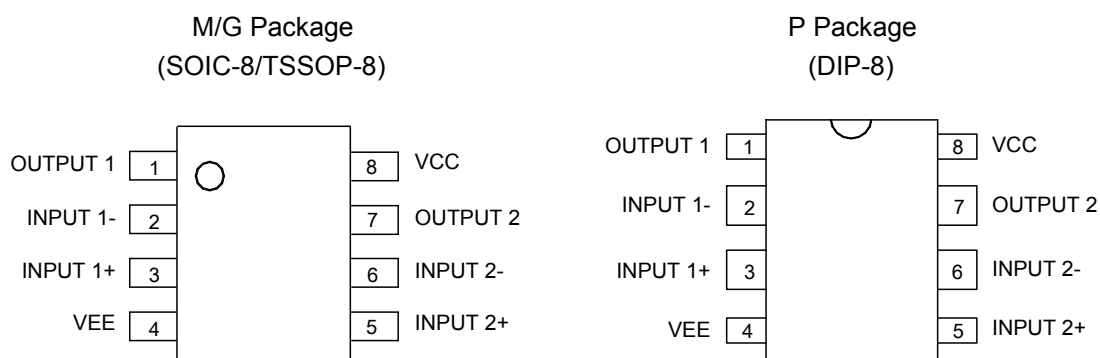


Figure 2. Pin Configuration of AZ4580

Pin Description

Pin No.	Function	Pin No.	Function	Pin No.	Function	Pin No.	Function
1	OUTPUT 1	2	INPUT 1-	3	INPUT 1+	4	VEE
5	INPUT 2+	6	INPUT 2-	7	OUTPUT 2	8	VCC

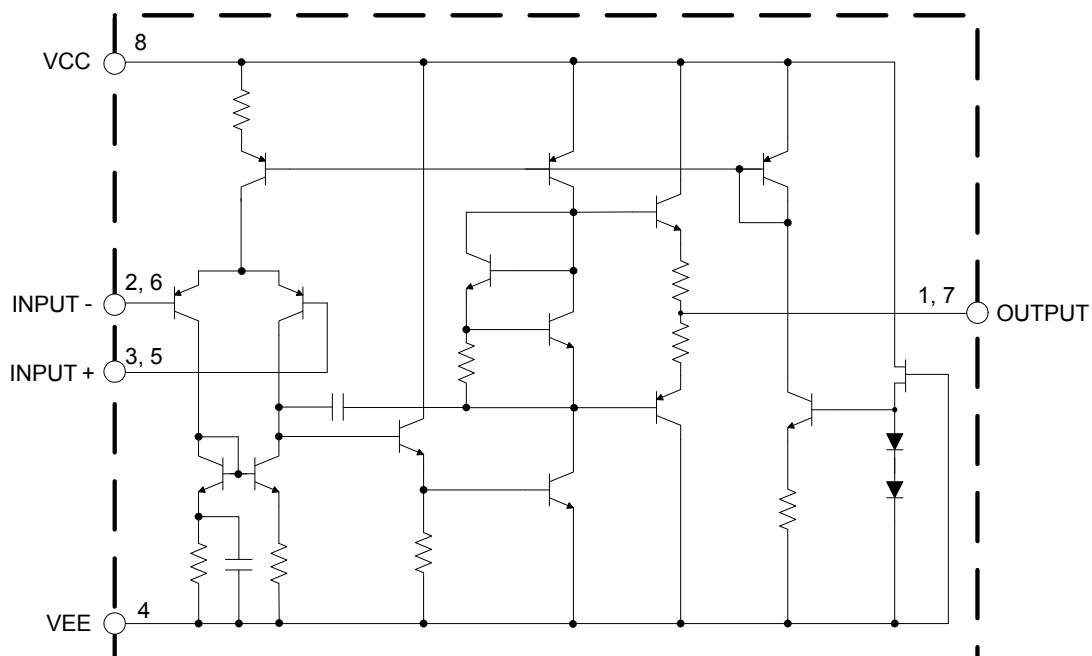
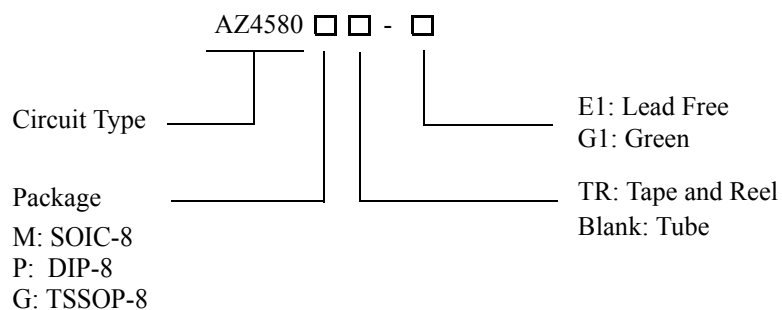
**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Functional Block Diagram**

Figure 3. Representative Schematic Diagram of AZ4580 (Each Amplifier)

**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Ordering Information**

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
SOIC-8	-40 to 85°C	AZ4580M-E1	AZ4580M-G1	4580M-E1	4580M-G1	Tube
		AZ4580MTR-E1	AZ4580MTR-G1	4580M-E1	4580M-G1	Tape & Reel
DIP-8	-40 to 85°C	AZ4580P-E1	AZ4580P-G1	AZ4580P-E1	AZ4580P-G1	Tube
TSSOP-8	-40 to 85°C	AZ4580GTR-E1	AZ4580GTR-G1	EG80	GG80	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Absolute Maximum Ratings (Note 1)**

Parameter	Smbol	Value		Unit
Power Supply Voltage	V _{CC}	+ 20		V
	V _{EE}	- 20		
Input Voltage	V _I	± 15		V
Differential Input Voltage	V _{ID}	± 30		V
Operating Junction Temperature	T _J	150		°C
Storage Temperature Range	T _{STG}	-65 to 150		°C
Lead Temperature (Soldering 10s)	T _L	260		°C
Power Dissipation (T _A =25°C)	P _D	TSSOP-8	400	mW
		SOIC-8	500	
		DIP-8	800	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Min	Max	Unit
Supply Voltage	± 2	± 18	V
Operating Temperature Range	-40	85	°C

**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Electrical Characteristics**Operating Conditions: $V_{CC}=+15V$, $V_{EE}=-15V$, $T_A=25^{\circ}C$ unless otherwise specified.

Parameter	Conditions	Min	Typ	Max	Unit
Supply Current	no load		4	7	mA
Input Offset Voltage	$R_S \leq 10K\Omega$		0.5	3	mV
Input Offset Current	$V_{CM}=0V$		5	100	nA
Input Bias Current	$V_{CM}=0V$		150	500	nA
Input Common Mode Voltage Range		± 12	± 13.5		V
Common Mode Rejection Ratio	$V_{CM}=0V$ to $V_{CC}-1.5V$, $R_S \leq 10K\Omega$	80	110		dB
Large Signal Voltage Gain	$R_L=2K\Omega$, $V_O=\pm 10V$	90	110		dB
Power Supply Rejection Ratio	$R_S \leq 10K\Omega$	80	110		dB
Output Sink Current	$V-=1V$, $V+=0V$, $V_O=2V$		80		mA
Output Source Current	$V+=1V$, $V-=0V$, $V_O=2V$		45		mA
Slew Rate	$R_L \geq 2K\Omega$		7		V/ μ S
Gain Bandwidth Product	$R_L=2K\Omega$, $f=10KHz$		15		MHz
Total Harmonic Distortion	$A_V=20dB$, $V_O=5V$ $R_L=2K\Omega$, $f=1KHz$		0.0005		%
Equivalent Input Noise Voltage	RIAA $R_S=50\Omega$, 30KHz LPF		0.7		μV_{RMS}
Thermal Resistance (Junction to Case)	DIP-8		43		$^{\circ}C/W$
	SOIC-8		63		



Typical Performance Characteristics

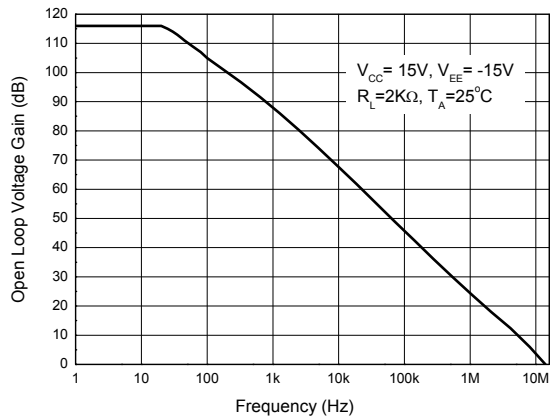


Figure 4. Open Loop Voltage Gain vs. Frequency

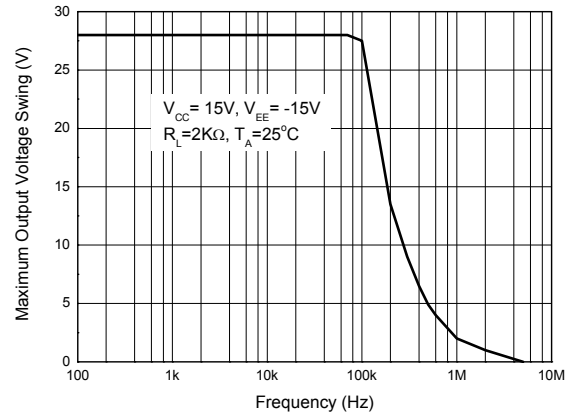


Figure 5. Maximum Output Voltage Swing vs. Frequency

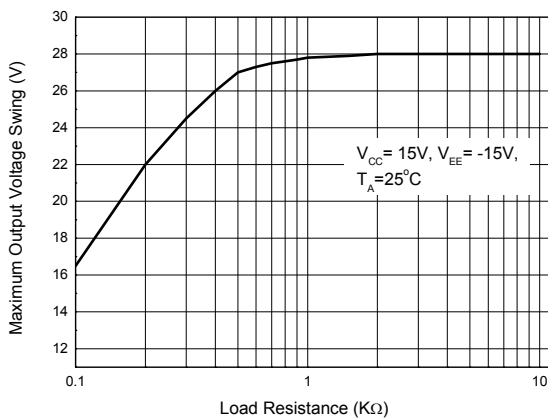


Figure 6. Maximum Output Voltage Swing vs. Load Resistance

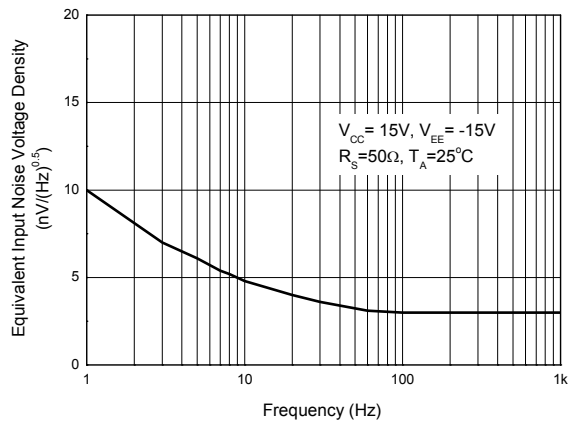


Figure 7. Equivalent Input Noise Voltage Density vs. Frequency

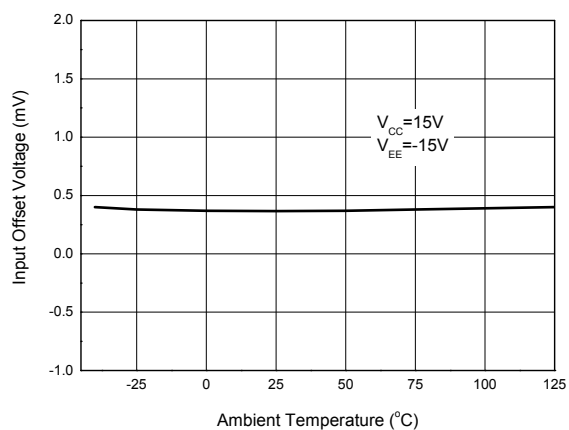
**Typical Performance Characteristics (Continued)**

Figure 8. Input Offset Voltage vs. Temperature

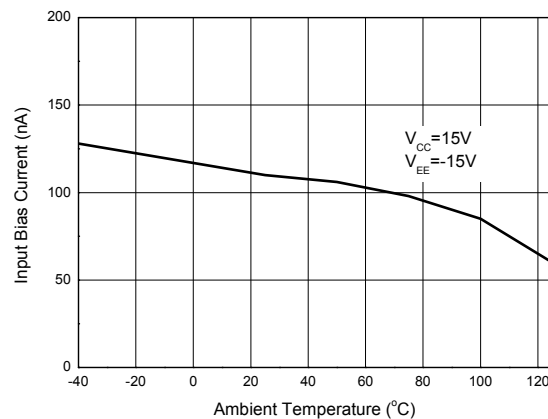


Figure 9. Input Bias Current vs. Temperature

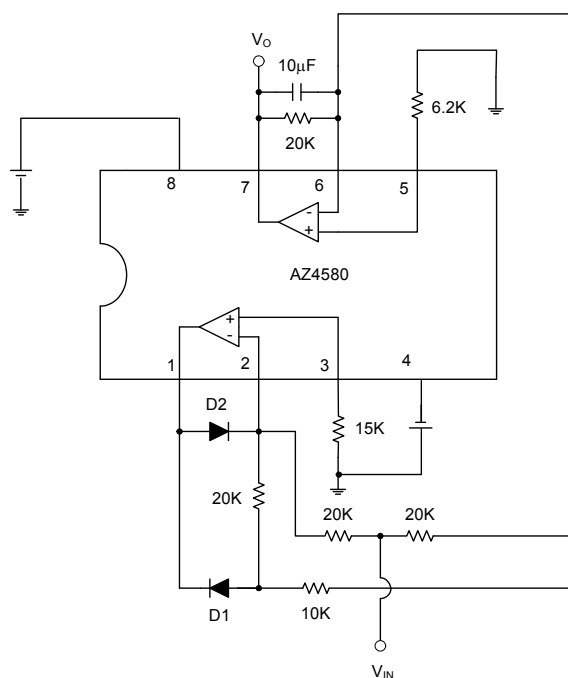
Typical Applications

Figure 10. Application of AZ4580 in an AC/DC Converter

Typical Applications (Continued)

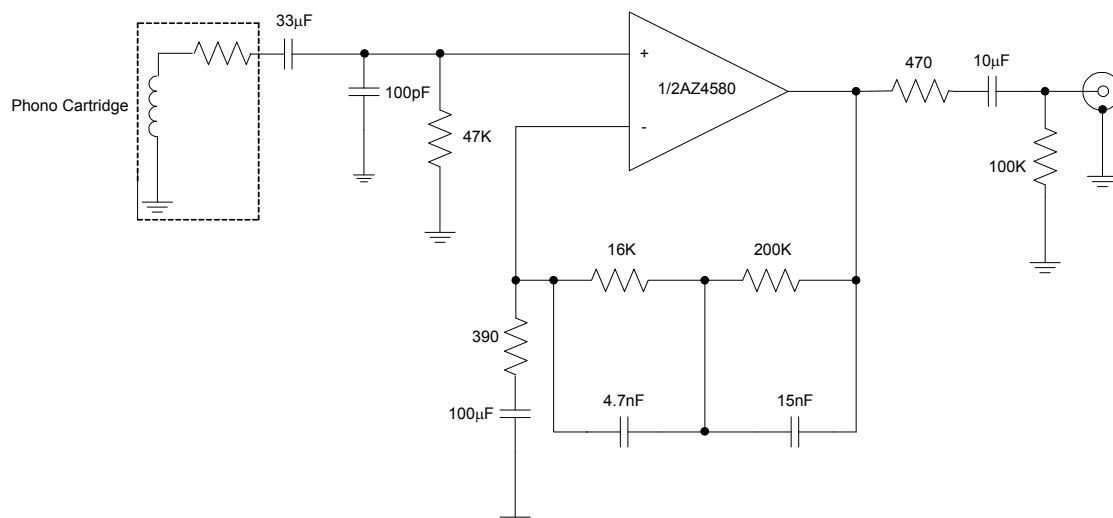


Figure 11. Application of AZ4580 in a RIAA Preamp

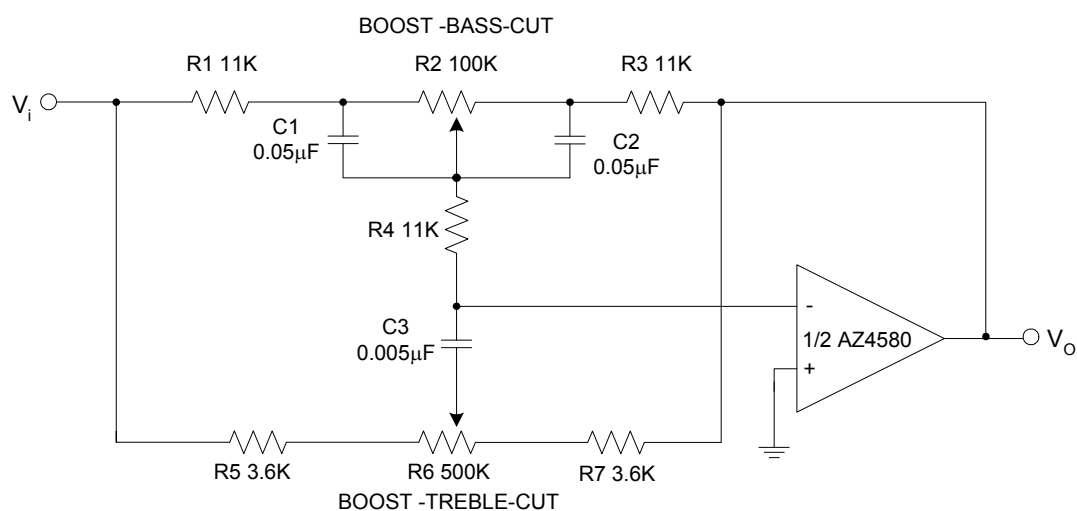
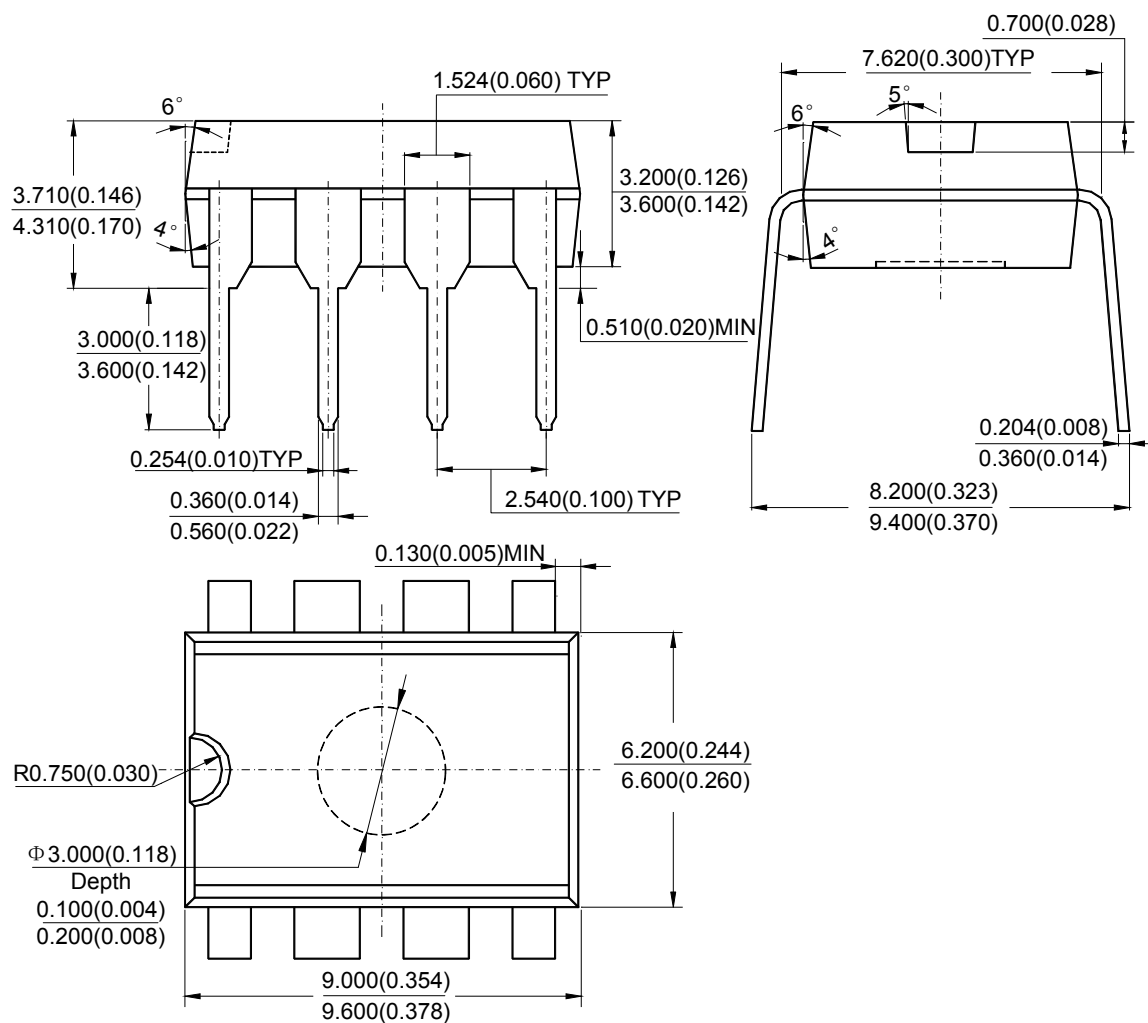
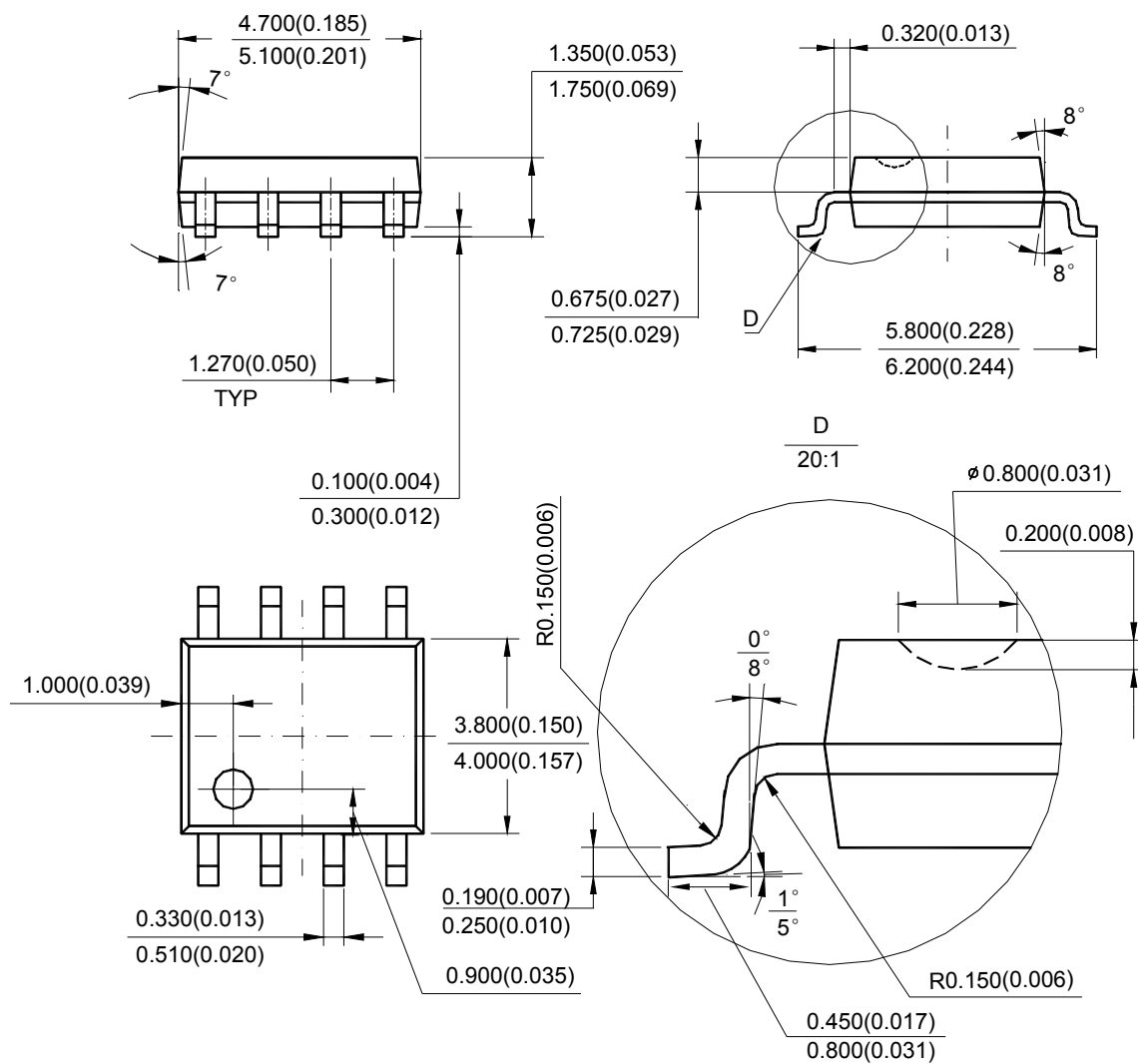


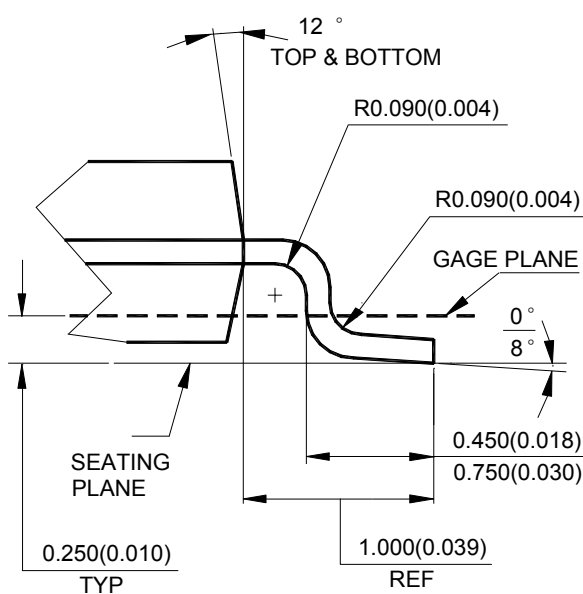
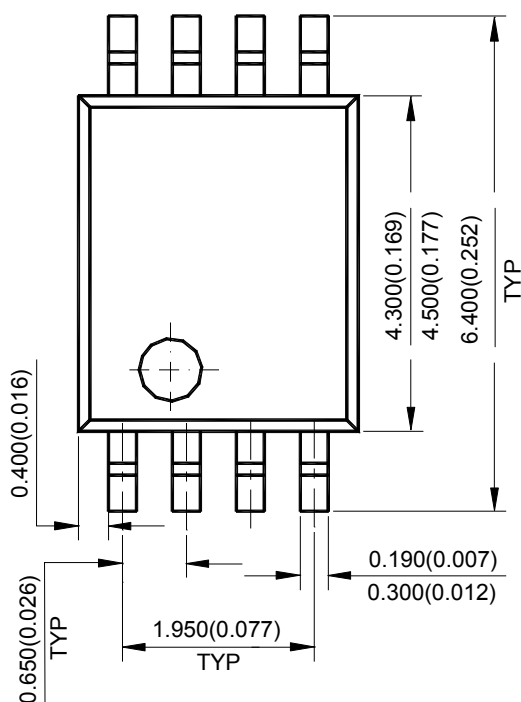
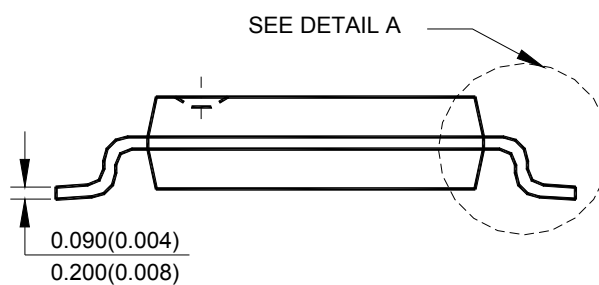
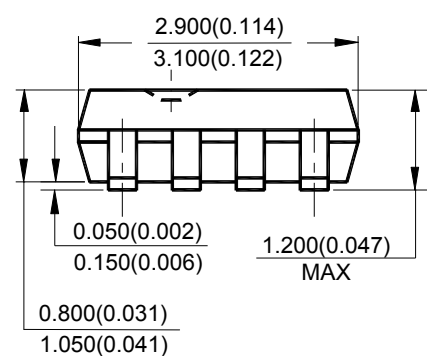
Figure 12. Application of AZ4580 in Tone Control

**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Mechanical Dimensions****DIP-8****Unit: mm(inch)**

Note: Eject hole, oriented hole and mold mark is optional.

**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Mechanical Dimensions (Continued)****SOIC-8****Unit: mm(inch)**

Note: Eject hole, oriented hole and mold mark is optional.

**DUAL LOW NOISE OPERATIONAL AMPLIFIERS****AZ4580****Mechanical Dimensions (Continued)****TSSOP-8****Unit: mm(inch)**

DETAIL A

Note: Eject hole, oriented hole and mold mark is optional.



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